NSN 5962-01-355-9503

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View Online at https://aerobasegroup.com/nsn/5962-01-355-9503

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|---|
| Body Length: |
| 0.560 inches |
| Body Width: |
| Between 0.442 inches and 0.458 inches |
| Body Height: |
| Between 0.060 inches and 0.120 inches |
| Maximum Power Dissipation Rating: |
| 1.04 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Hermetically sealed and burn in and monolithic and 3-state output and electrostatic sensitive |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Leadless flat pack |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 14 input |
| Case Outline Source And Designator: |
| C-12 mil-m-38510 |
| Current Rating Per Characteristic: |
| 190.00 milliamperes reverse current, dc absolute |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -0.3 volts power source and 7.0 volts power source |
| Capitance Rating Per Characteristic: |
| 10.00 input picofarads and 13.00 output picofarads |
| Time Rating Per Chacteristic: |
| 100.00 nanoseconds access |
| Memory Device Type: |
| Prom |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 32 leadless |
| Shelf Life: |

N/a

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Demilitarization:

Yes - demil/mli

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